

## Features

- GaN-on Silicon E-mode HEMT technology
- Very low gate charge
- Ultra low On-resistance
- Very small footprint

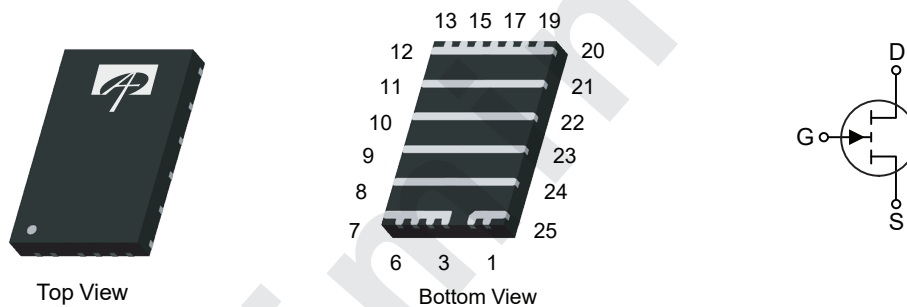
## Applications

- High frequency DC/DC converter
- Solar systems optimizers and microinverters
- PD charger and PSU synchronous rectification
- Telecom power supply
- Motor driver

## Product Summary at $T_J = 25^\circ\text{C}$

$V_{DS, \text{max}}$	150V
$R_{DS(\text{on}), \text{max}} @ V_{GS} = 5V$	3.9m $\Omega$
$Q_g, \text{typ} @ V_{DS} = 75V$	20nC
$I_{DS, \text{Pulse}}$	260A
$Q_{oss} @ V_{DS} = 75V$	130nC

## Pin Configuration



## Pin Information

Pin	Pin Description	Pin Function
1, 2, 25	Gate	Driver Gate
3-7, 9, 11, 21, 23	Source	Source
8, 10, 12-20, 22, 24	Drain	Power Drain

## Ordering Information

Ordering Part Number	Package Type	Form	Shipping Quantity
AOFQ039V15GA1	FCQFN4x6	Tape and Reel	1500

Contact local sales office for full product datasheet.

## Absolute Maximum Ratings

( $T_J = 25^\circ\text{C}$ , unless otherwise noted)

Symbol	Parameter	AOFQ039V15GA1	Units
$V_{DS}$	Drain-Source Voltage (Continuous)	150	V
$V_{DS(\text{tr})}$	Drain-Source Voltage (up to 300,000 5ms pulse at $150^\circ\text{C}$ )	180	
$I_D$	Continuous Drain Current	100	A
	Pulsed ( $25^\circ\text{C}$ , $T_{\text{Pulse}} = 100\mu\text{s}$ )	260	
$V_{GS}$	Gate-Source Voltage	-4 to 6	V
$T_{J, \text{stg}}$	Operating and Storage Temperature	-40 to 150	$^\circ\text{C}$

## Thermal Characteristics

Symbol	Parameter	Typ	Max	Note	Units
$R_{\theta JA}$	Thermal Resistance Junction-to-Ambient <sup>(1)</sup>	57.56			°C/W
$R_{\theta JB}$	Thermal Resistance Junction-to-Board	1.92			°C/W
$R_{\theta JC}$	Thermal Resistance Junction-to-Case	13.96			°C/W
$T_{\text{sold}}$	Maximum Reflow Soldering Temperature	260		MSL3	°C

## Electrical Characteristics

( $T_J = 25^{\circ}\text{C}$ , unless otherwise noted)

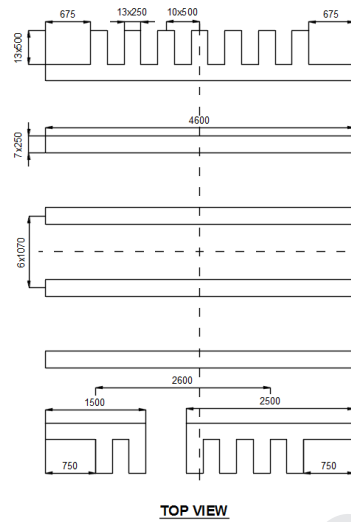
Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>STATIC PARAMETERS</b>						
$BV_{DSS}$	Drain-Source Voltage	$V_{GS} = 0\text{ V}, I_D = 500\mu\text{A}$	150			V
$I_{DSS}$	Drain-Source Leakage	$V_{DS} = 150\text{V}, V_{GS} = 0\text{V}$		2	150	$\mu\text{A}$
$I_{GSS}$	Gate-Source Forward Leakage	$V_{GS} = 5\text{V}$		2	100	$\mu\text{A}$
	Gate-Source Forward Leakage	$V_{GS} = 6\text{V}$		6	1000	$\mu\text{A}$
	Gate-Source Reverse Leakage	$V_{GS} = -4\text{V}$		0.1	100	$\mu\text{A}$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 12\text{mA}$	0.8	1.1	2.1	V
$R_{DS(on)}$	Drain-Source On-State-Resistance	$V_{GS} = 5\text{V}, I_D = 30\text{A}$		3.2	3.9	m $\Omega$
$V_{SD}$	Source-Drain Forward Voltage	$I_S = 0.5\text{A}, V_{GS} = 0\text{V}$		1.5		V
<b>DYNAMIC</b>						
$C_{ISS}$	Input Capacitance	$V_{GS} = 0\text{V}, V_{DS} = 75\text{V}$		2200		pF
$C_{OSS}$	Output Capacitance	$V_{GS} = 0\text{V}, V_{DS} = 75\text{V}$		900		
$C_{RSS}$	Reverse Transfer Capacitance	$V_{GS} = 0\text{V}, V_{DS} = 75\text{V}$		10.5		
$C_{OSS(ER)}$	Energy Related $C_{OSS}$	$V_{GS} = 0\text{V}, V_{DS} = 0\text{V to } 75\text{V}$		1300		
$C_{OSS(TR)}$	Time Related $C_{OSS}$	$V_{GS} = 0\text{V}, V_{DS} = 0\text{V to } 75\text{V}$		1700		
$R_G$	Gate Resistance	$f = 5\text{MHz}, \text{open drain}$		2		$\Omega$
$Q_G$	Total Gate Charge	$V_{GS} = 5\text{V}, V_{DS} = 75\text{V}, I_D = 30\text{A}$		20		nC
$Q_{GS}$	Gate-Source Charge	$V_{DS} = 75\text{V}, I_D = 30\text{A}$		5		
$Q_{GD}$	Gate-Drain Charge	$V_{DS} = 75\text{V}, I_D = 30\text{A}$		3.5		
$Q_{G(TH)}$	Gate Charge at Threshold	$V_{DS} = 75\text{V}, I_D = 30\text{A}$		3		
$Q_{OSS}$	Output Charge	$V_{GS} = 0\text{V}, V_{DS} = 75\text{V}$		130		

### Note:

- $R_{\theta JA}$  is determined with the device mounted on one square inch of copper pad, single layer 2oz copper on FR4 board.

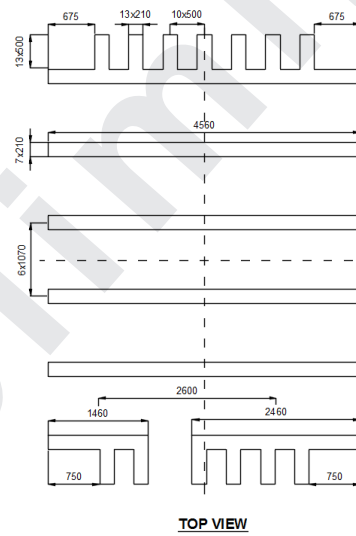
## Land Pattern, FCQFN4x6

### Recommended Land Pattern



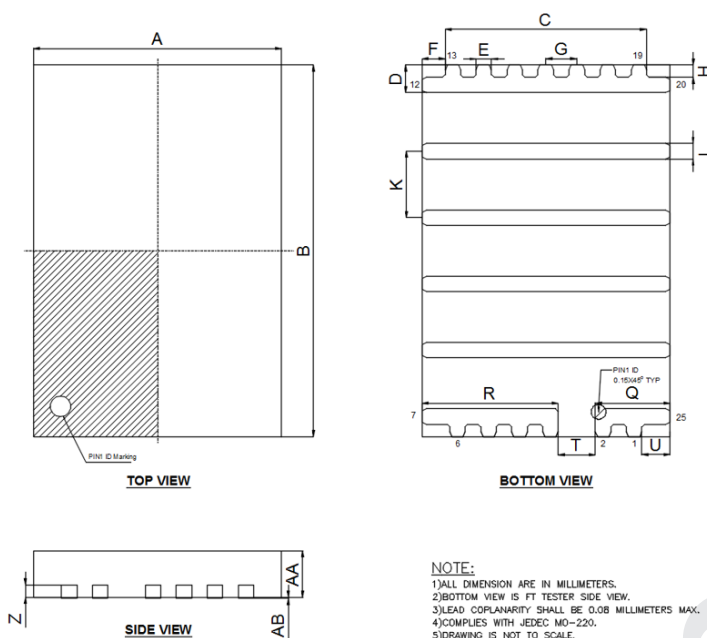
Unit:  $\mu\text{m}$

### Recommended Stencil Drawing



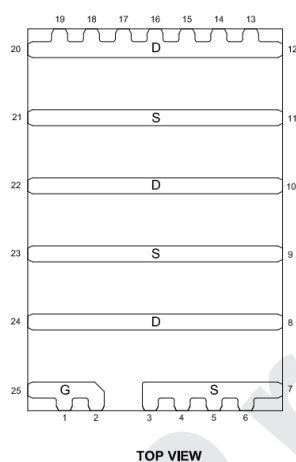
Unit:  $\mu\text{m}$

## Package Dimensions, FCQFN4x6

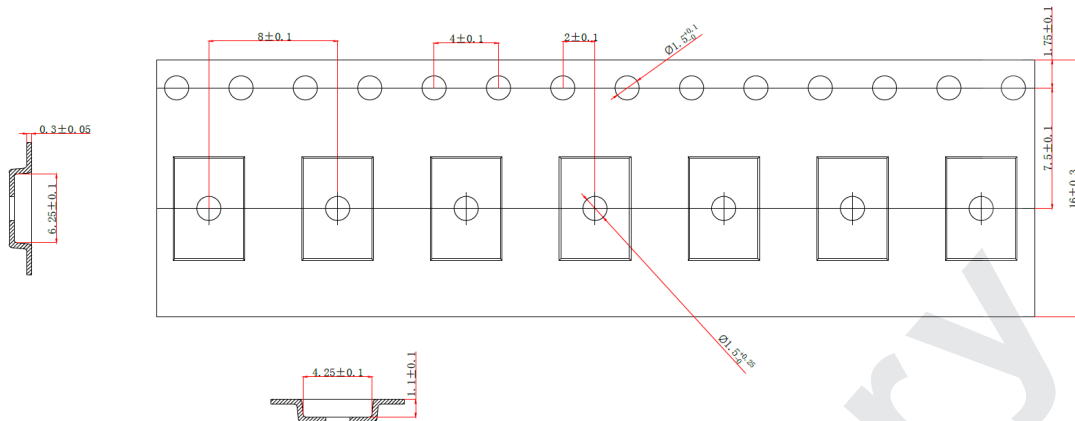


SYMBOL	MILLIMETER			NOTE
	MIN	NOM	MAX	
A	3.9	4.0	4.1	
B	5.9	6.0	6.1	
C	3.15	3.25	3.35	
D	0.35	0.45	0.55	3X
E	0.20	0.25	0.30	13X
F		0.375 REF		2X
G		0.5 BASIC		10X
H		0.2 REF		3X
K		1.07 BASIC		6X
L	0.20	0.25	0.30	4X
Q	1.1	1.2	1.3	
R	2.1	2.2	2.3	
T	0.55	0.60	0.65	
U		0.45 REF		2X
Z		0.203 REF		7X
AA	0.75	0.85	0.95	
AB	0.00	0.02	0.05	

## PIN Configuration

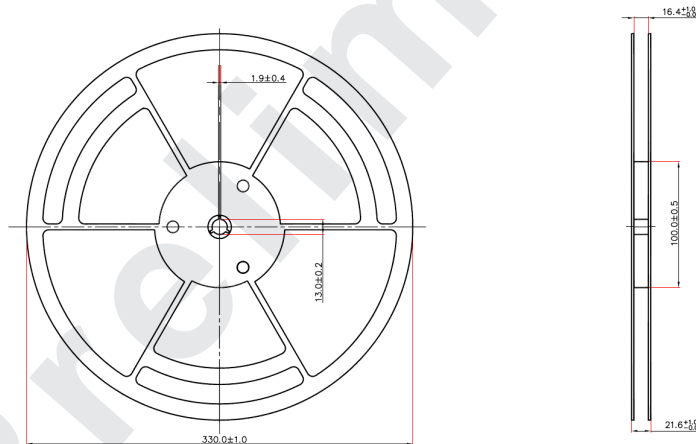


## Tape and Reel Dimensions, FCQFN4x6



### NOTES:

1. CARRIER TAPE COLOR: BLACK.
2. COVER TAPE WIDTH: 13.3±0.10.
3. COVER TAPE COLOR: TRANSPARENT.
4. 10 SPROCKET HOLE PITCH CUMULATIVE TOLERANCE ±0.20 MAX.
5. CAMBER NOT TO EXCEED 1MM IN 100MM.
6. MOLD# QFN/DFN/MIS6X4X0.75/0.85.
7. ALL DIMS IN MM.
8. BAN TO USE THE ENVIRONMENT-RELATED SUBSTANCES OF JCET PRESCRIBING.



### NOTES:

1. 2500 UNITS PER TRAY.
2. COLOR: WHITE.
3. ALL DIM IN mm.
4. GENERAL TOLERANCE±0.25.
5. BAN TO USE THE ENVIRONMENT-RELATED SUBSTANCES OF JCET PRESCRIBING.
6. THE DIRECTION OF VIEW:

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